MOSFET - Single, N-Channel, Small Signal, ESD Protection, SC-70/SOT-323 25 V, 0.75 A

Features

- Advance Planar Technology for Fast Switching, Low R_{DS(on)}
- Higher Efficiency Extending Battery Life
- AEC-Q101 Qualified and PPAP Capable NVS4409N
- These Devices are Pb-Free and are RoHS Compliant

Applications

- Boost and Buck Converter
- Load Switch
- Battery Protection

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Ratin	Symbol	Value	Unit		
Drain-to-Source Voltage	V _{DSS}	25	V		
Gate-to-Source Voltage			V _{GS}	±8.0	V
Drain Current	t < 5 s	T _A = 25°C	I _D	0.75	Α
Continuous Drain Current	Steady T _A = 25°C		I _D	0.7	Α
(Note 1)	State	T _A = 75°C		0.6	
Power Dissipation (Note 1)	Stead	dy State	P_{D}	0.28	W
Power Dissipation (Note 1)	t s	≤ 5 s	P_{D}	0.33	W
Pulsed Drain Current	t _p =	10 μs	I _{DM}	3.0	Α
Operating Junction and Sto	T _J , T _{STG}	-55 to +150	°C		
Source Current (Body Dioc	Is	0.3	Α		
Lead Temperature for Sold (1/8" from case for 10 s)	TL	260	°C		
ESD Rating - Machine Mo		25	V		

THERMAL RESISTANCE RATINGS

Rating	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 1)	$R_{\theta JA}$	450	°C/W
Junction-to-Ambient - t ≤ 5 s (Note 1)	$R_{\theta JA}$	375	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

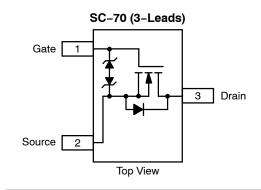
1. Surface mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [1 oz] including traces).



ON Semiconductor®

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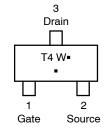
V _{(BR)DSS}	V _{(BR)DSS} R _{DS(on)} Typ	
25 V	249 m Ω @ 4.5 V	0.75 A
	299 mΩ @ 2.7 V	0.75 A



MARKING DIAGRAM & PIN ASSIGNMENT



SC-70/SOT-323 CASE 419 STYLE 8



T4 = Device Code W = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
NTS4409NT1G	SOT-323 (Pb-Free)	3000 / Tape & Reel
NVS4409NT1G	SOT-323 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Characteristic	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS	•		•		•	•	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		25			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J				30		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	I _{DSS}				0.5	μΑ
		$V_{GS} = 0 V$, $V_{DS} = 20 V$	T _J = 70°C			2.0	
			T _J = 125°C			5.0	
Gate-to-Source Leakage Current	I _{GSS}	$V_{DS} = 0 V, V_{C}$	_{SS} = 8.0 V			100	nA
ON CHARACTERISTICS (Note 2)							
Gate Threshold Voltage	V _{GS(TH)}	V _{GS} = V _{DS} , I _D	₀ = 250 μA	0.65		1.5	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J				-2.0		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 0.6 A			249	350	mΩ
	$V_{GS} = 2.7 \text{ V, } I_{D}$ $V_{GS} = 4.5 \text{ V, } I_{D}$		I _D = 0.2 A		299	400	
			I _D = 1.2 A		260		
Forward Transconductance	9FS	V _{DS} = 5.0 V, I _D = 0.5 A			0.5		S
CHARGES AND CAPACITANCES							-
Input Capacitance	C _{ISS}	V _{GS} = 0 V, f = 1.0 MHz, V _{DS} = 10 V			49	60	pF
Output Capacitance	C _{OSS}				22.4	30	
Reverse Transfer Capacitance	C _{RSS}	• 03 – .	Ĭ		8.0	12	
Total Gate Charge	Q _{G(TOT)}				1.2	1.5	nC
Threshold Gate Charge	Q _{G(TH)}	V _{GS} = 4.5 V, V	ns = 15 V,		0.2		
Gate-to-Source Charge	Q_{GS}	$I_D = 0.8$	BA		0.28	0.50	
Gate-to-Drain Charge	Q_{GD}				0.3	0.40	
SWITCHING CHARACTERISTICS (No	ote 3)						-
Turn-On Delay Time	t _{d(ON)}	V_{GS} = 4.5 V, V_{DS} = 15 V, I_{D} = 0.7 A, R_{G} = 51 Ω			5.0	12	ns
Rise Time	t _r				8.2	8.0	
Turn-Off Delay Time	t _{d(OFF)}				23	35	
Fall Time	t _f				41	60	
DRAIN-SOURCE DIODE CHARACTE	RISTICS		•		-	-	•
Forward Diode Voltage	V _{SD}	V _{GS} = 0 V, I _S = 0.6 A	T _J = 25°C		0.82	1.20	V

Pulse Test: pulse width ≤ 300 μs, duty cycle ≤ 2%.
 Switching characteristics are independent of operating junction temperatures.

TYPICAL PERFORMANCE CURVES (T_J = 25°C unless otherwise noted)

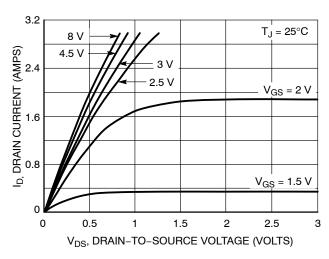


Figure 1. On-Region Characteristics

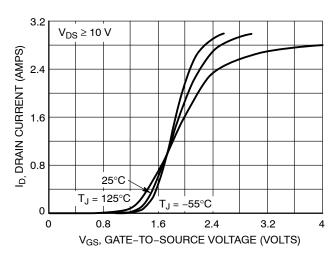


Figure 2. Transfer Characteristics

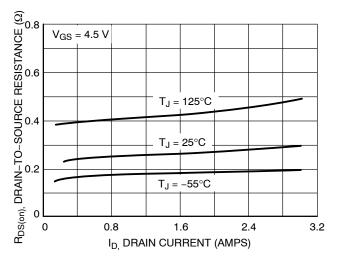


Figure 3. On-Resistance vs. Drain Current and Temperature

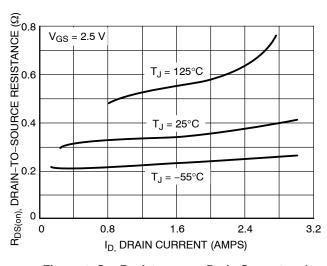


Figure 4. On-Resistance vs. Drain Current and Gate Voltage

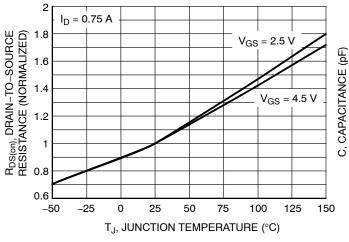


Figure 5. On–Resistance Variation with Temperature

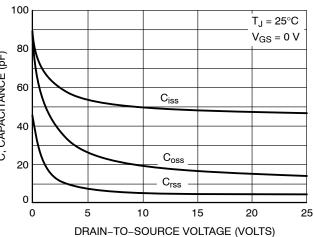


Figure 6. Capacitance Variation

TYPICAL PERFORMANCE CURVES ($T_J = 25^{\circ}$ C unless otherwise noted)

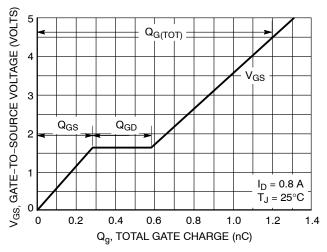


Figure 7. Gate-to-Source and Drain-to-Source Voltage vs. Total Charge

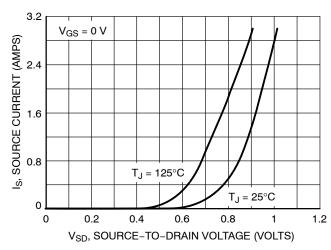
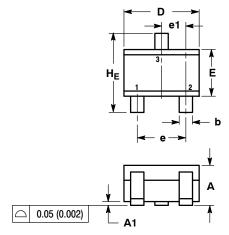


Figure 8. Diode Forward Voltage vs. Current

PACKAGE DIMENSIONS

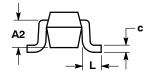
SC-70 (SOT-323) CASE 419-04 ISSUE N



NOTES:

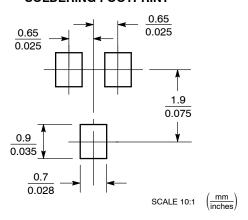
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.70 REF			0.028 REF		
b	0.30	0.35	0.40	0.012	0.014	0.016
C	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
Е	1.15	1.24	1.35	0.045	0.049	0.053
е	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC			0.026 BSC		
L	0.20	0.38	0.56	0.008	0.015	0.022
HE	2.00	2.10	2.40	0.079	0.083	0.095



STYLE 8: PIN 1. GATE 2. SOURCE 3. DRAIN

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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